

INVERTER GRADE THYRISTORS

Stud Version

Features

- Center amplifying gate
- All diffused design
- Guaranteed high dv/dt
- Guaranteed high di/dt
- Low thermal impedance
- High speed performance

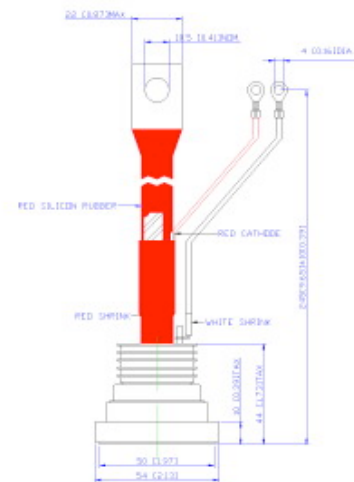
290A

Typical Applications

- Induction heating
- Choppers
- force-commutated converters

Major Ratings and Characteristics

| Parameters | T290.. | Units |
|---------------------|-------------|------------------|
| $I_{T(AV)}$ | 290 | A |
| | @ T_c | 65 °C |
| $I_{T(RMS)}$ | 455 | A |
| I_{TSM} | @ 50Hz | 5000 A |
| | @ 60Hz | 5230 A |
| $I^2 t$ | @ 50Hz | 300 KA^2s |
| | @ 60Hz | 280 KA^2s |
| V_{DRM} / V_{RRM} | 400 to 1600 | V |
| T_q | typical | 10 to 25 μs |
| T_J | range | - 40 to 115 °C |



case style
TO-209AE (TO-118)

ELECTRICAL SPECIFICATIONS
Voltage Ratings

| Type number | Voltage Code | V_{RRM} / V_{DRM} , maximum repetitive peak reverse voltage V | V_{RSM} , maximum non-repetitive peak rev. voltage V | I_{RRM} / I_{DRM} max. @ $T_J = T_J$ max. mA |
|-------------|--------------|--|---|--|
| T290.. | 04 | 400 | 500 | 50 |
| | 08 | 800 | 900 | |
| | 12 | 1200 | 1300 | |
| | 14 | 1400 | 1500 | |
| | 16 | 1600 | 1700 | |

On-state Conduction

| Parameter | T290.. | Units | Conditions | |
|--|-----------|--------------------|--|----------------|
| $I_{T(AV)}$ Maximum average on-state current @ Case temperature | 290 | A | 180° conduction, half sine wave | |
| | 65 | °C | | |
| $I_{(RMS)}$ Maximum RMS on-state current | 455 | A | 180° conduction, half sine wave @ $T_C = 80^\circ\text{C}$ | |
| I_{TSM} Maximum peak, one-cycle non-repetitive surge current | 5000 | A | t = 10ms | No voltage |
| | 5230 | | t = 8.3ms | reapplied |
| | 4200 | | t = 10ms | 100% V_{RRM} |
| | 4400 | | t = 8.3ms | reapplied |
| $I^2 t$ Maximum $I^2 t$ for fusing | 300 | KA ² s | t = 10ms | No voltage |
| | 280 | | t = 8.3ms | reapplied |
| | 180 | | t = 10ms | 100% V_{RRM} |
| | 165 | | t = 8.3ms | reapplied |
| $I^2 \sqrt{t}$ Maximum $I^2 \sqrt{t}$ for fusing | 2600 | KA ² √s | t = 0.1 to 10ms, no voltage reapplied | |
| V_{TM} Maximum on-state or forward | 2.60 | V | pk = 900A, $T_J = 25^\circ\text{C}$, t p = 10ms sine pulse | |
| I_H Maximum holding current | 600 | mA | $T_J = 25^\circ\text{C}$, anode supply 12V resistive load | |
| I_L Typical latching current | 1000(300) | | | |
| r ₁₁ Low level value of forward slope resistance | 0.7 | mΩ | $(16.7\% \times \pi \times I_{T(AV)} < I < \pi \times I_{T(AV)})$, $T_J = T_J$ max. | |

Switching

| Parameter | T290.. | Units | Conditions |
|--|----------|-------|--|
| di/dt ax. non-repetitive rate of rise of turned-on current | 1000 | A/μs | Gate drive 20V, 20Ω, t _r ≤ 1μs $T_J = T_J$ max, anode voltage ≤ 80% V_{DRM} |
| t _d ical delay time | 1.0 | μs | Gate current 1A, dig/dt = 1A/μs $V_d = 0.67\% V_{DRM}$, $T_J = 25^\circ\text{C}$ |
| T _q pical turn-off time | 10 to 25 | μs | $I_{TM} = 500\text{A}$, $T_J = T_J$ max, di/dt = 40A/μs, $V_R = 50\text{V}$ dv/dt = 20V/μs, Gate 0V 100Ω, t _p = 500μs |

Blocking

| Parameter | T290.. | Units | Conditions |
|---|--------|-------|---|
| dv/dt Maximum critical rate of rise of off-state voltage | 500 | V/μs | T _J = T _J max linear to 80% rated V _{DRM} |
| I _{DRM} Max. peak reverse and off-state leakage current | 30 | mA | T _J = T _J max, rated V _{DRM} /V _{RRM} applied |

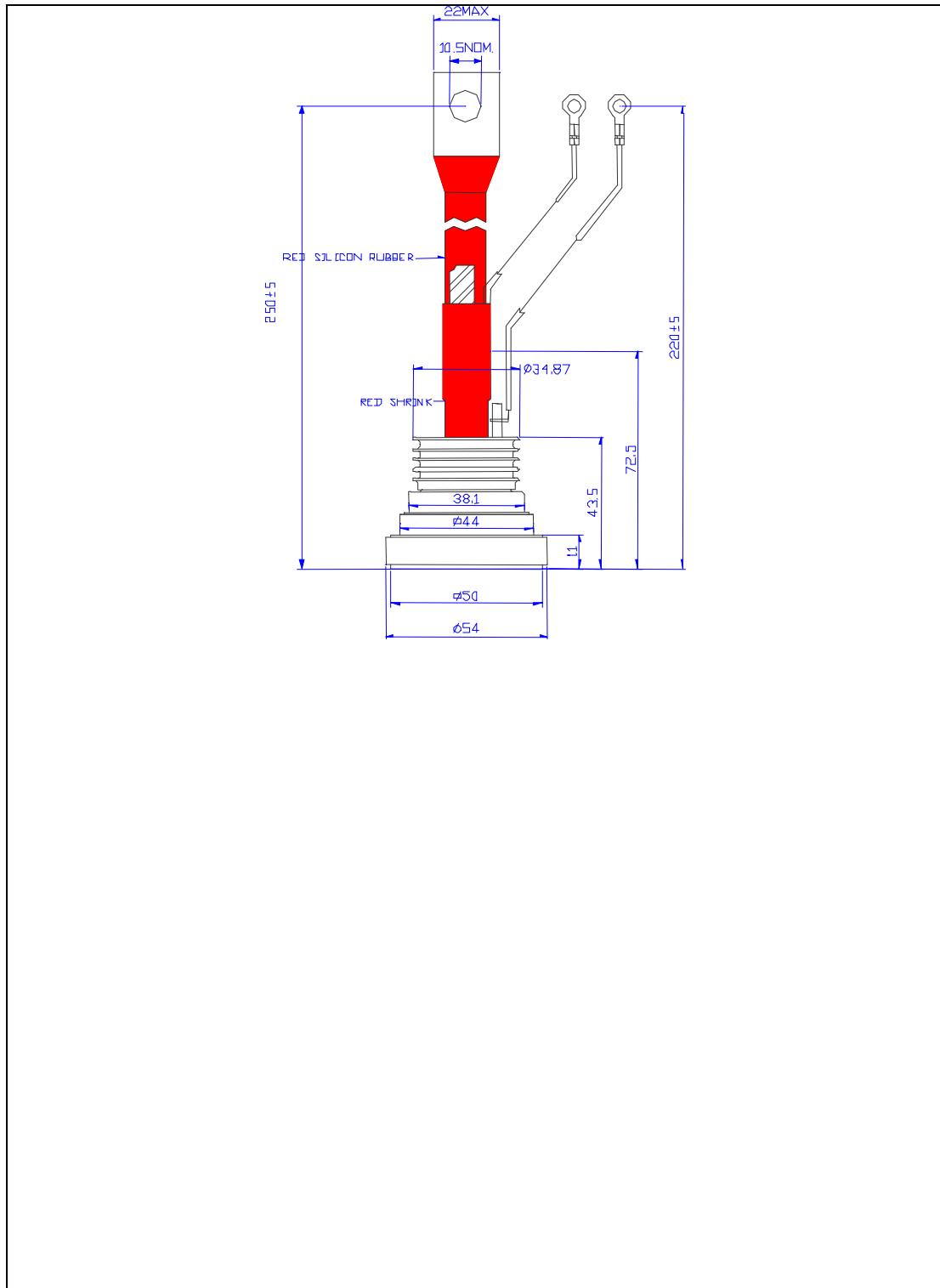
Triggering

| Parameter | T290.. | Units | Conditions |
|--|--------|-------|---|
| P _{GM} Maximum peak gate power | 70 | W | T _J = T _J max, t _p ≤ 5ms |
| P _{G(AV)} Maximum average gate power | 11 | | T _J = T _J max, f = 50Hz, d% = 50 |
| I _{GM} Max. peak positive gate current | 9 | A | T _J = T _J max, t _p ≤ 5ms |
| +V _{GM} Maximum peak positive gate voltage | 20 | V | T _J = T _J max, t _p ≤ 5ms |
| -V _{GM} Maximum peak negative gate voltage | 5.0 | | |
| I _{GT} DC gate current required to trigger | TYP. | MAX. | T _J = - 40°C T _J = 25°C T _J = 115°C Max. required gate trigger/ current/ voltage are the lowest value which will trigger all units 12V anode-to-cathode applied |
| | 180 | - | |
| | 90 | 150 | |
| V _{GT} DC gate voltage required to trigger | 2.9 | - | T _J = - 40°C T _J = 25°C T _J = 115°C |
| | 1.8 | 3.0 | |
| | 1.2 | - | |
| I _{GD} DC gate current not to trigger | 20 | mA | T _J = T _J max Max. gate current/ voltage not to trigger is the max. value which will not trigger any unit with rated V anode-to-cathode applied |
| V _{GD} DC gate voltage not to trigger | 0.25 | V | |

Thermal and Mechanical Specification

| Parameter | T290.. | Units | Conditions |
|--|------------|-------|--|
| T _J Max. operating temperature range | -40 to 115 | °C | |
| T _{stg} Max. storage temperature range | -40 to 130 | | |
| R _{thJC} Max. thermal resistance, junction to case | 0.15 | K/W | DC operation |
| R _{thCS} Max. thermal resistance, case to heatsink | 0.03 | | Mounting surface, smooth, flat and greased |
| T Mounting torque, ± 10% | 48.5 | Nm | Non lubricated threads |
| wt Approximate weight | 500 | g | |

Outline Table



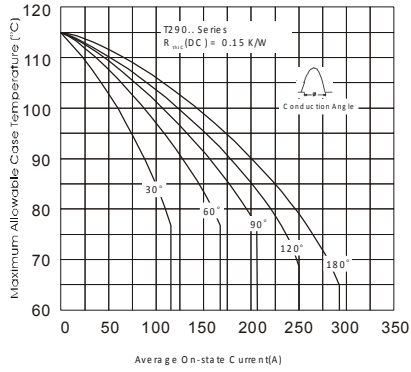


Fig. 1 - Current Ratings Characteristics

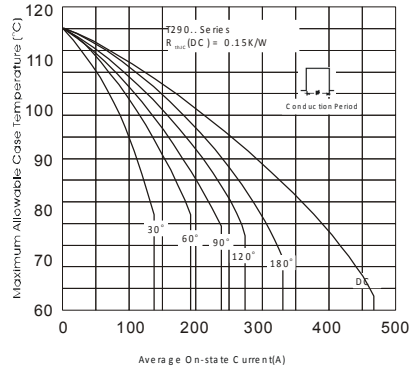


Fig. 2 - Current Ratings Characteristics

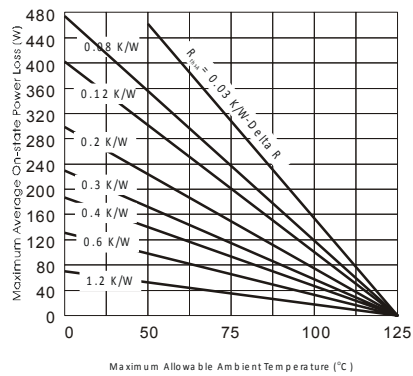
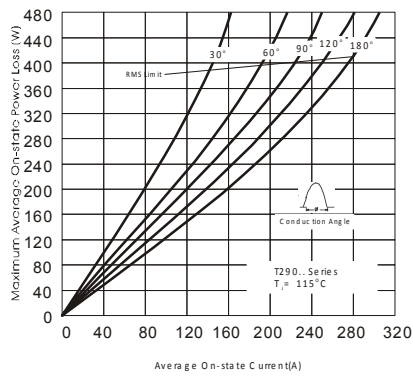


Fig. 3 - On-state Power Loss Characteristics